

WIR SCHAFFEN WISSEN – HEUTE FÜR MORGEN



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A. Zandonella

Photocathodes for SwissFEL

- SwissFEL Introduction
- Photocathode Experience at SwissFEL
- Cs₂Te coating (successive, co-evaporation)
- Cs₃Sb coating attempts
- Conclusion and perspectives

- **SwissFEL Introduction**
- Photocathode Experience at SwissFEL
- Cs_2Te coating (successive, co-evaporation)
- Cs_3Sb coating attempts
- Conclusion and perspectives

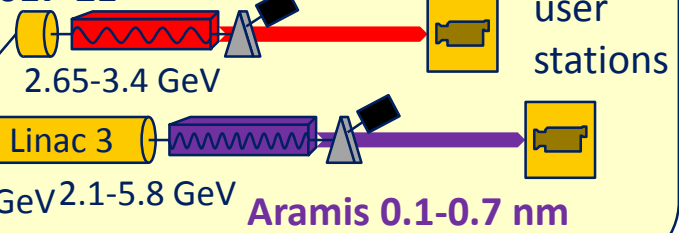


PSI West

PSI East

**Hard X-Ray FEL
740 m Long
First Beam End 2016**

SwissFEL

1st Construction Phase**2013-16****2nd Construction Phase****2017-21****Aramis**

Linear polarization, variable gap, in-vacuum
Undulators

First users 2018

Athos

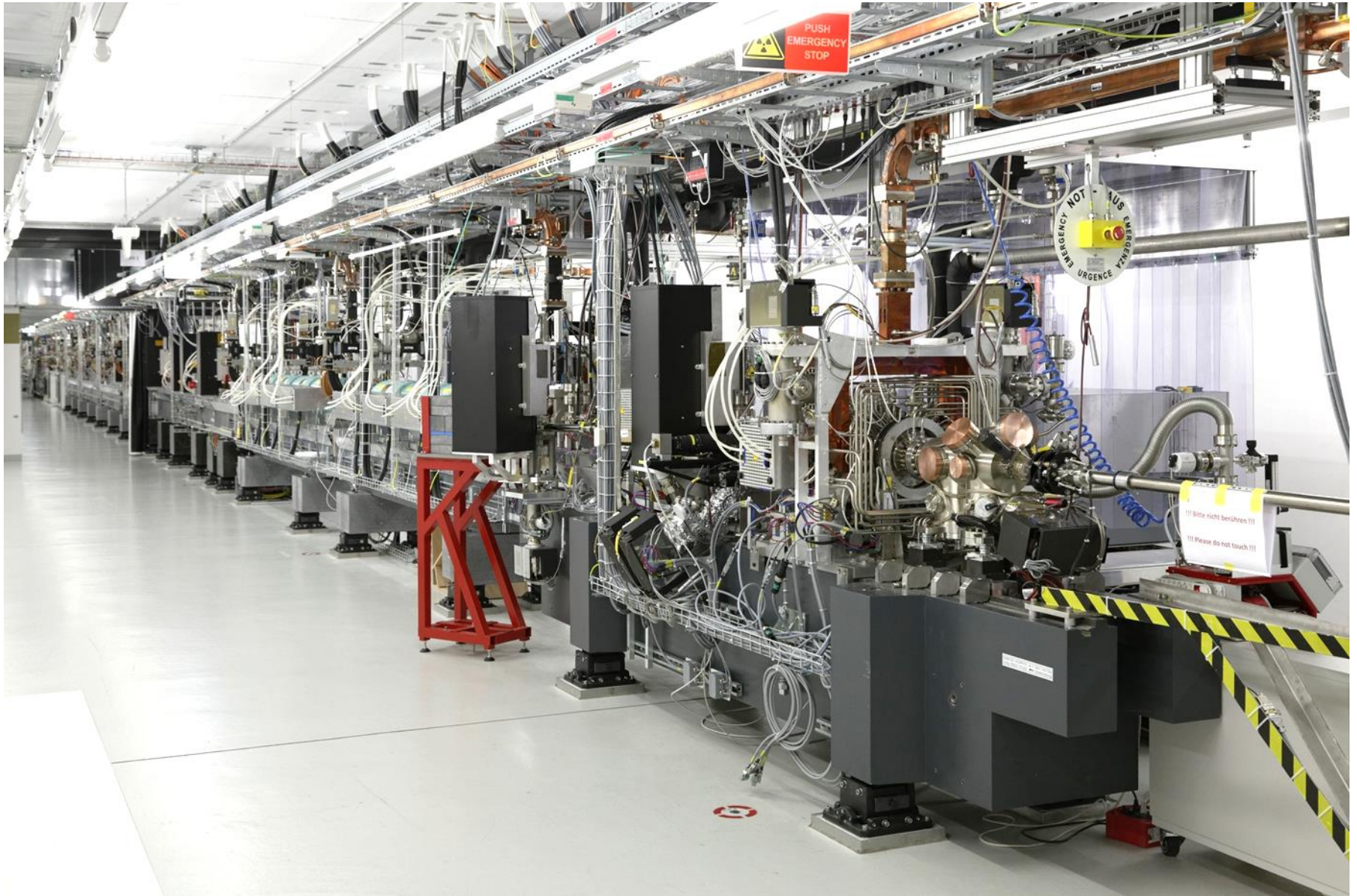
Soft X-ray FEL, variable polarisation

First users 2021

Aramis Main parameters

Photon energy	2 – 12.4 keV
Pulse duration	20 fs
e ⁻ Energy	2.1 - 5.8 GeV
e ⁻ Bunch charge	10-200 pC
Repetition rate	100 Hz

SwissFEL Electron Gun and Loadlock

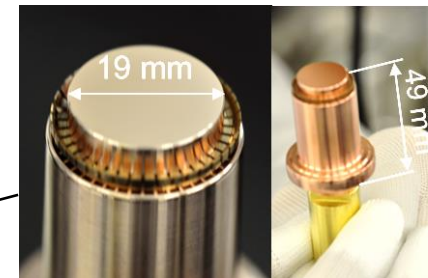
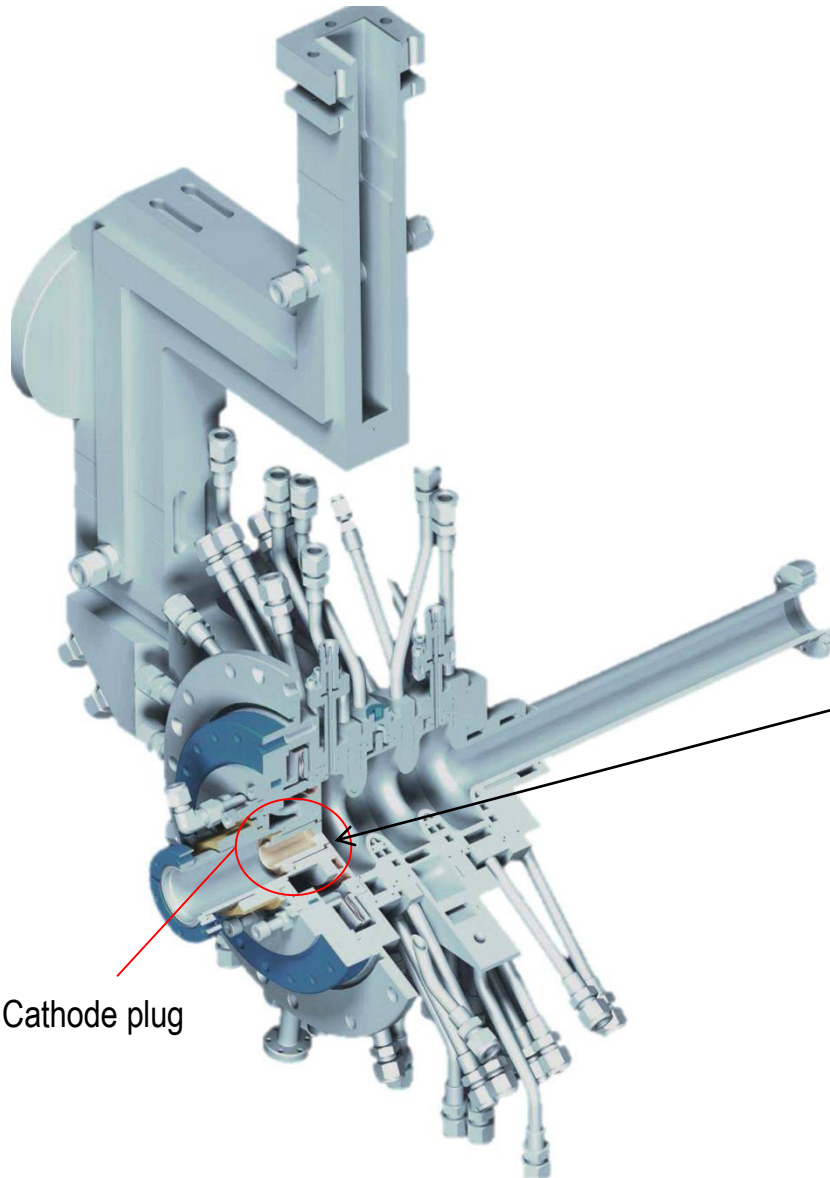


SwissFEL RF Photoinjector

SwissFEL RF Photoinjector:

S band, 2.5 Cell; 7 MeV;

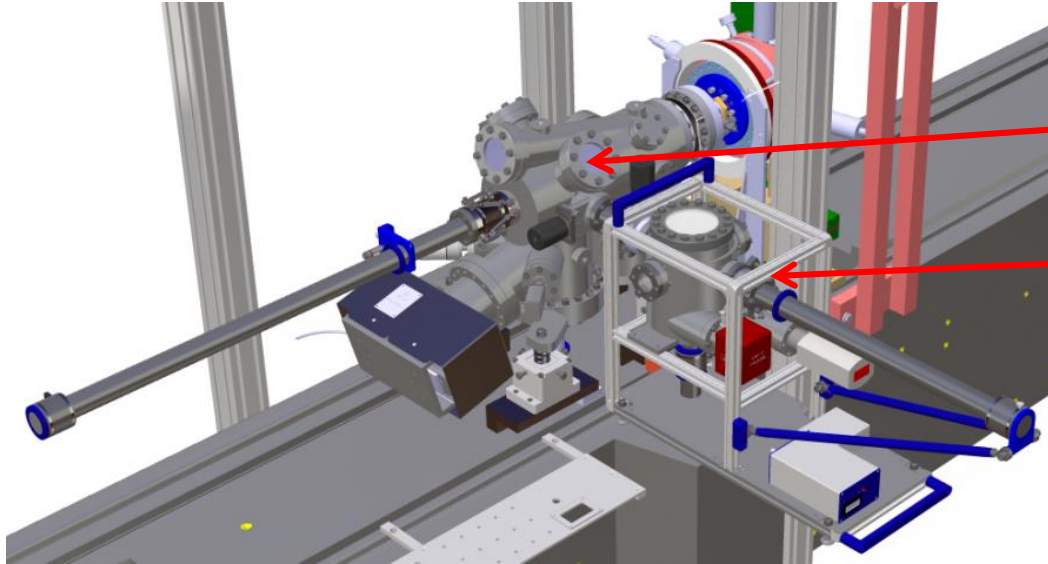
100 MV/m; 100 Hz; 10 - 200 pC



Exchangeable cathode plug(*)

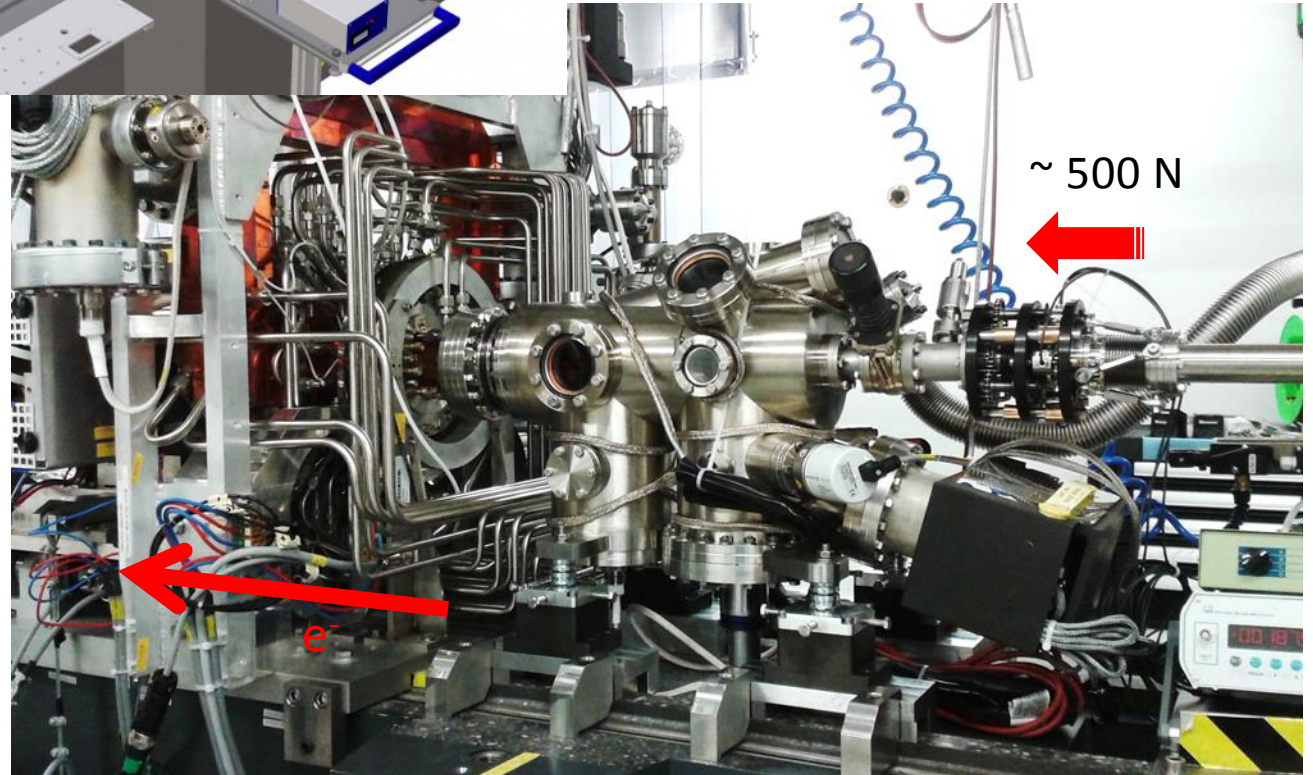
(*) CERN design: CLIC Note 303 (1996)

Loadlock chamber behind RF gun



Loadlock chamber

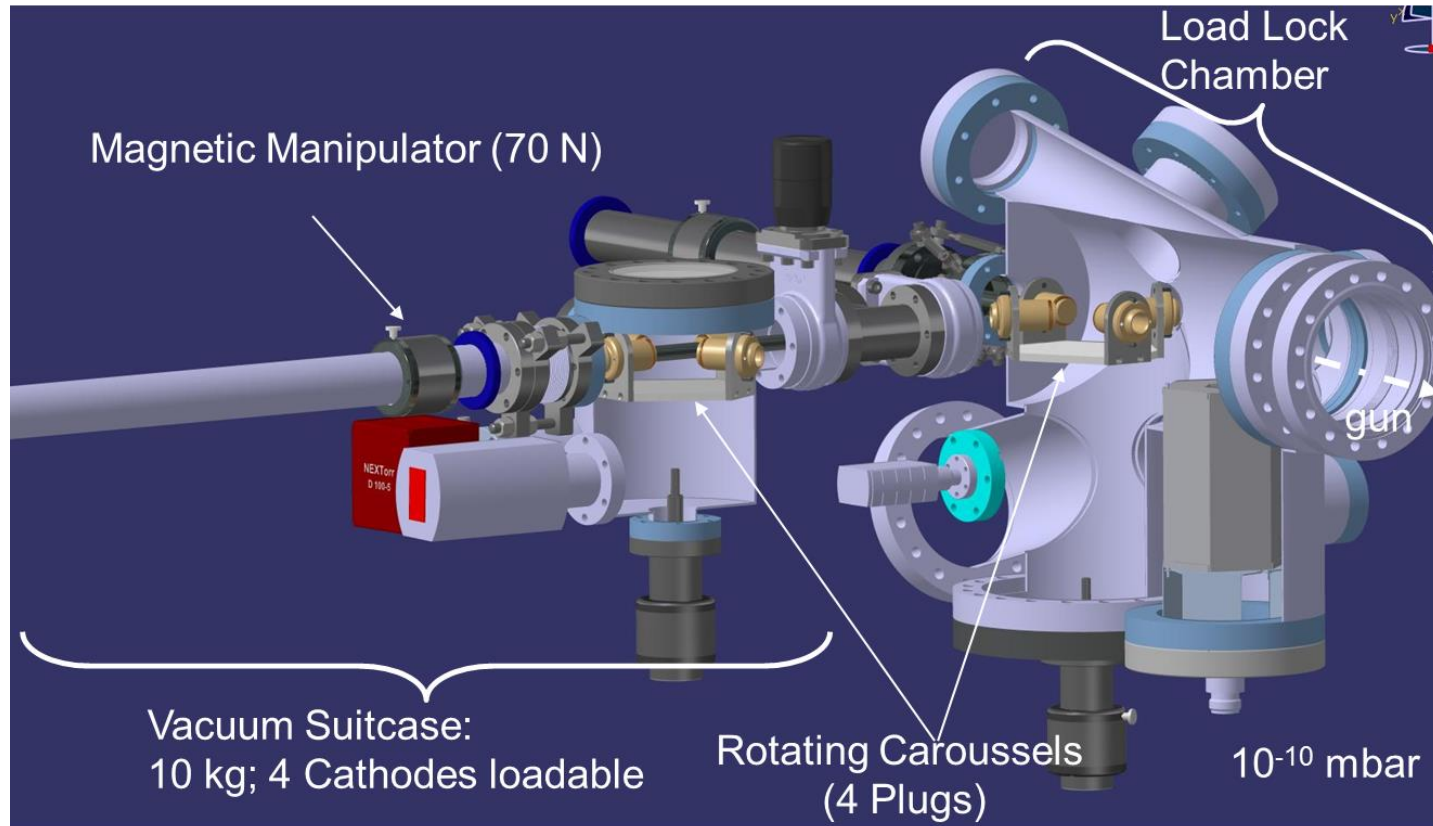
Vacuum suitcase



~ 500 N

e^-

Loadlock chamber for SwissFEL



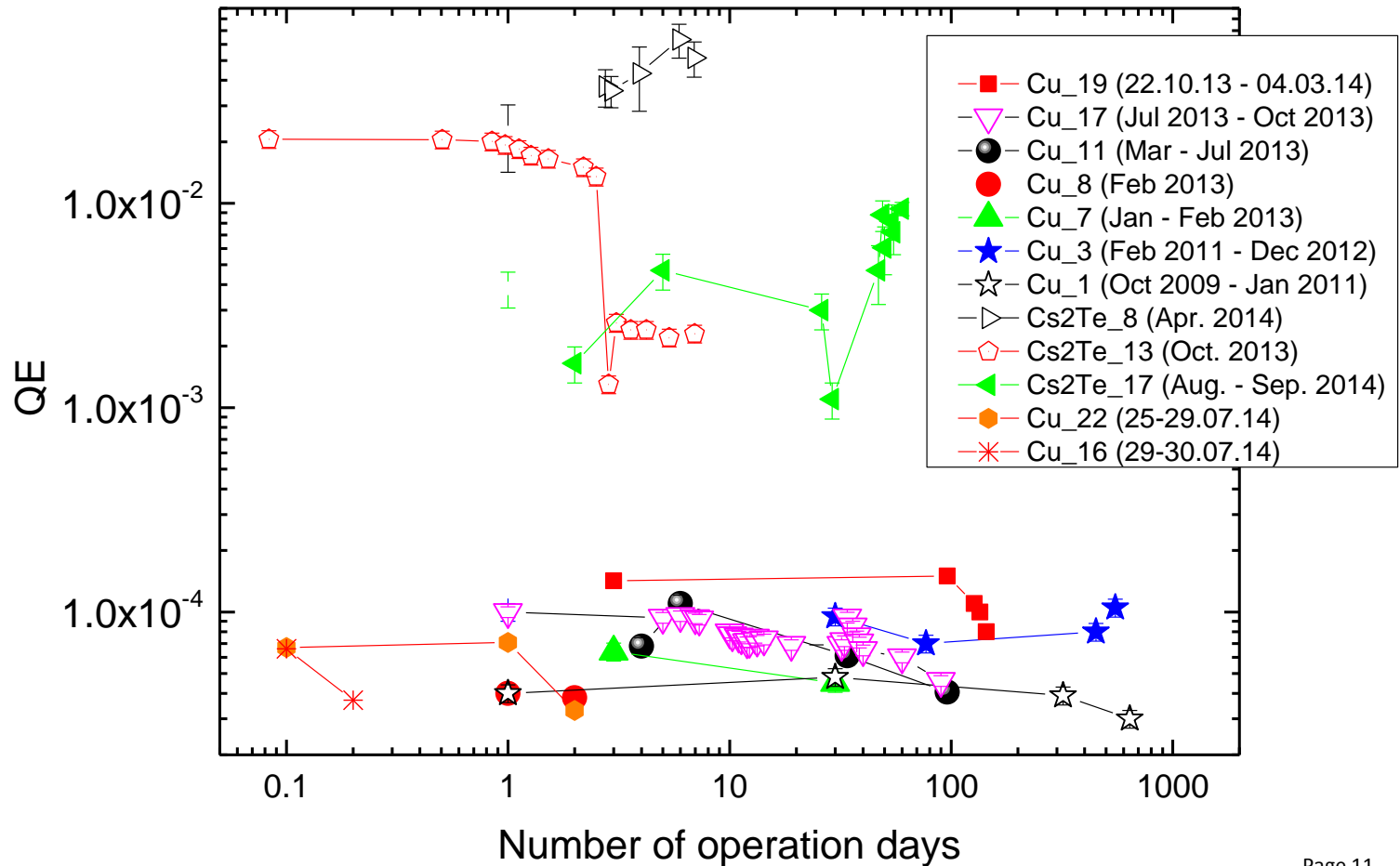
Vacuum suitcase connected to the load-lock, showing the cathode transfer principle and the storage carroussels..

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Loadlock installed in 2013 at the SITF:

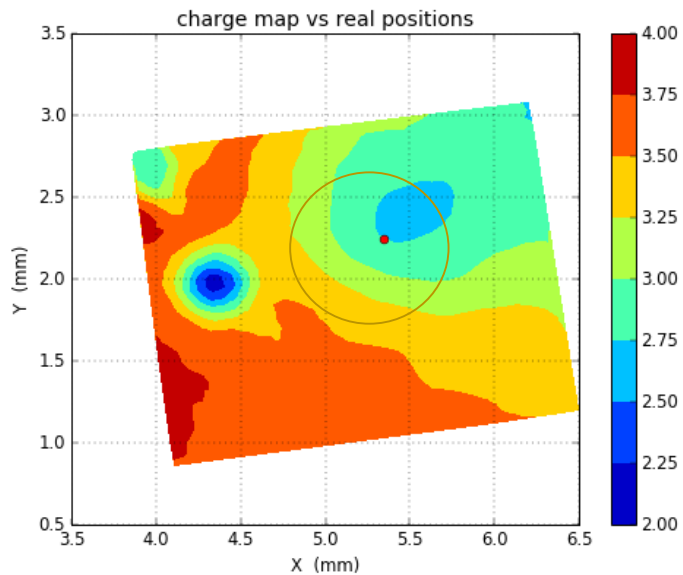
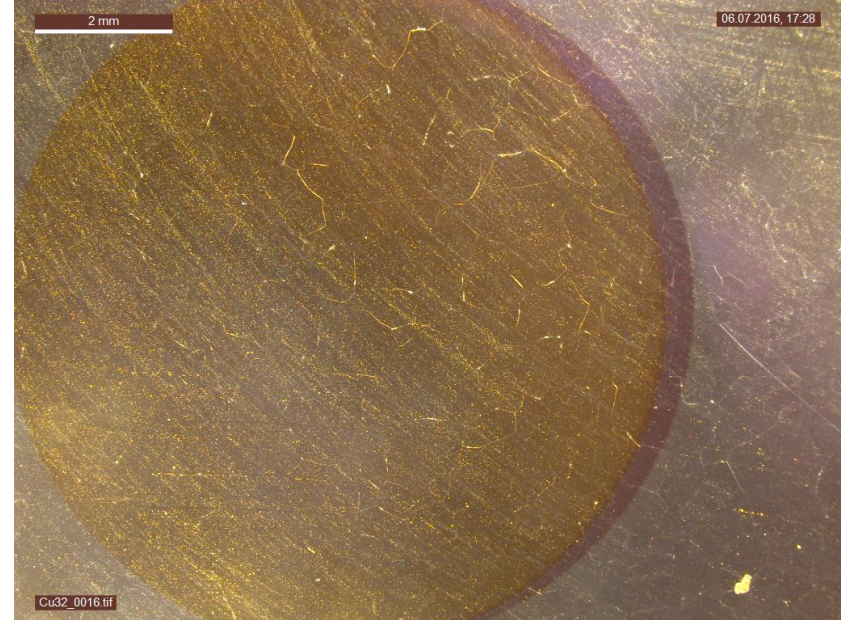
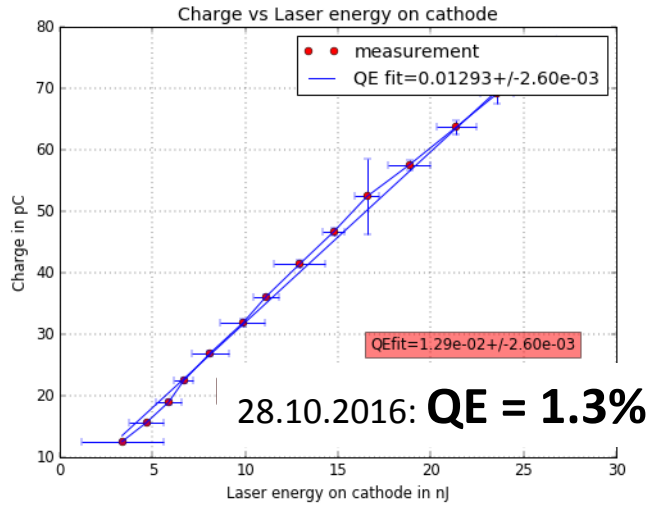
=> Recipe to get reproducible copper $QE_{Cu} \sim 10^{-4}$

=> First test of Cs_2Te Cathodes: $QE \sim 10^{-2}$



- 2015: Decision to operate SwissFEL only with Cs₂Te
- 2016: Gun + Loadlock moved to SwissFEL

From October 2016 to July 2017: Cathode #32



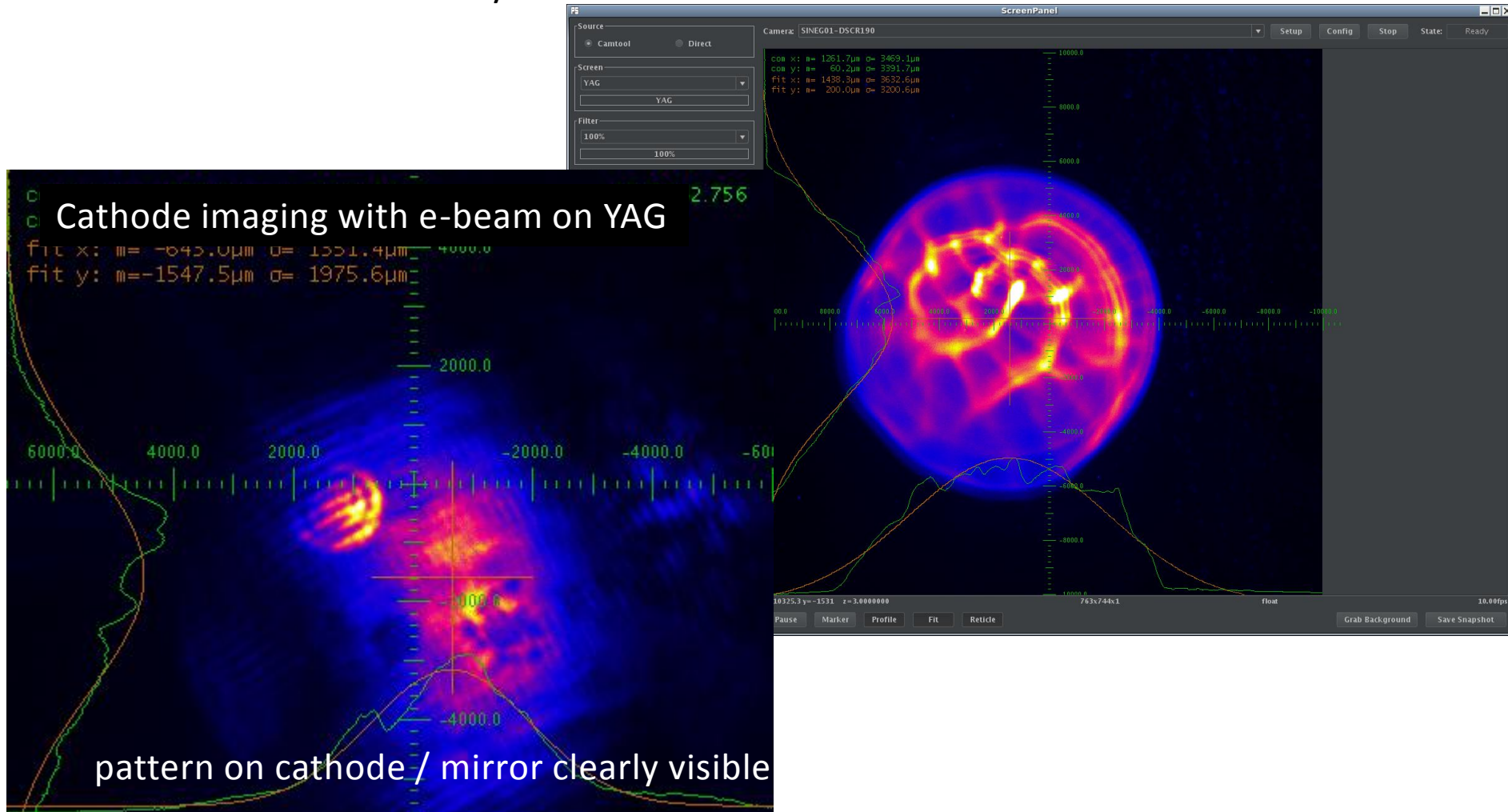
04.07.2017:
QE ~ 1.3%
 $\delta_{QE}/QE \sim 15\%$

Cathode#32: Cs₂Te by co-evaporation ;
very thin layer < 20nm

No QE decay in 10 Months

Why was cathode exchanged ?

Electron Beam uniformity issues

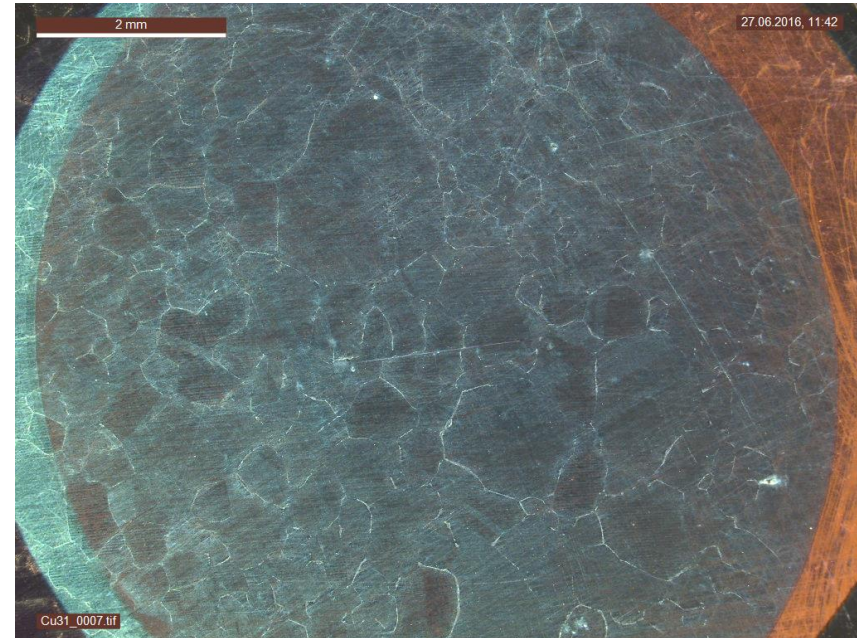
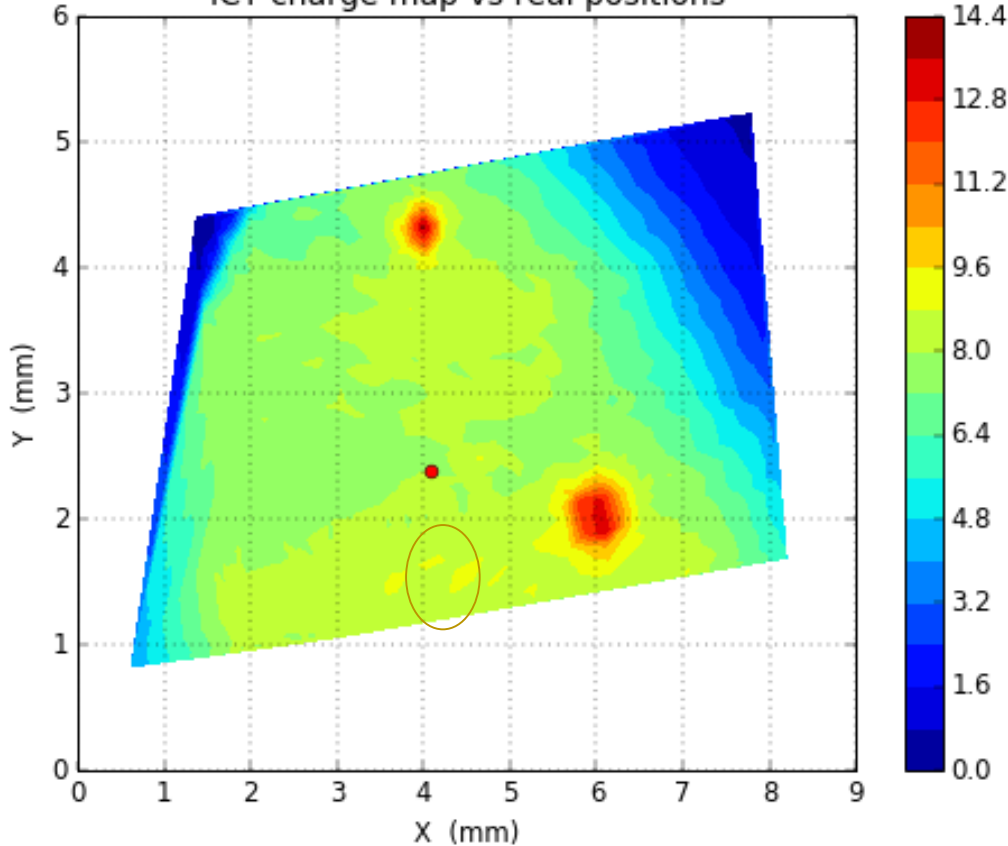


⇒ Exchanged cathode on July 21st 2017

⇒ Cs₂Te detached at some area (dark spot visible by eye)

From October 2016 to July 2017: Cathode #31

ICT charge map vs real positions

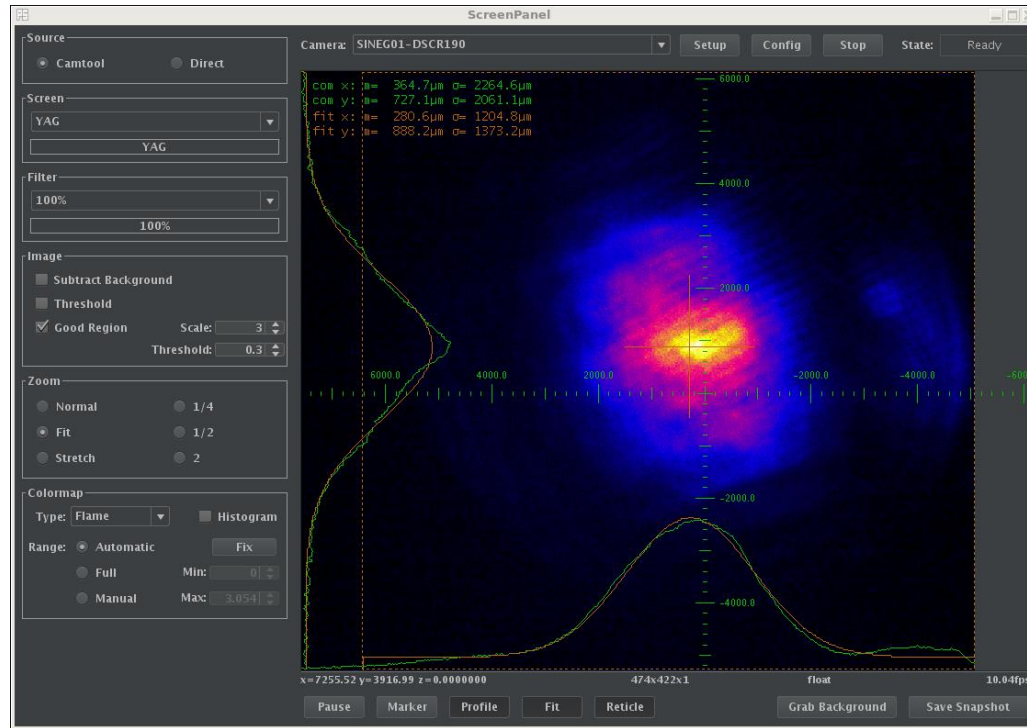


Cathode#31: Cs₂Te by successive evaporation ; ~ **40nm**

24.07.2017:

Averaged QE ~ 0.6 %

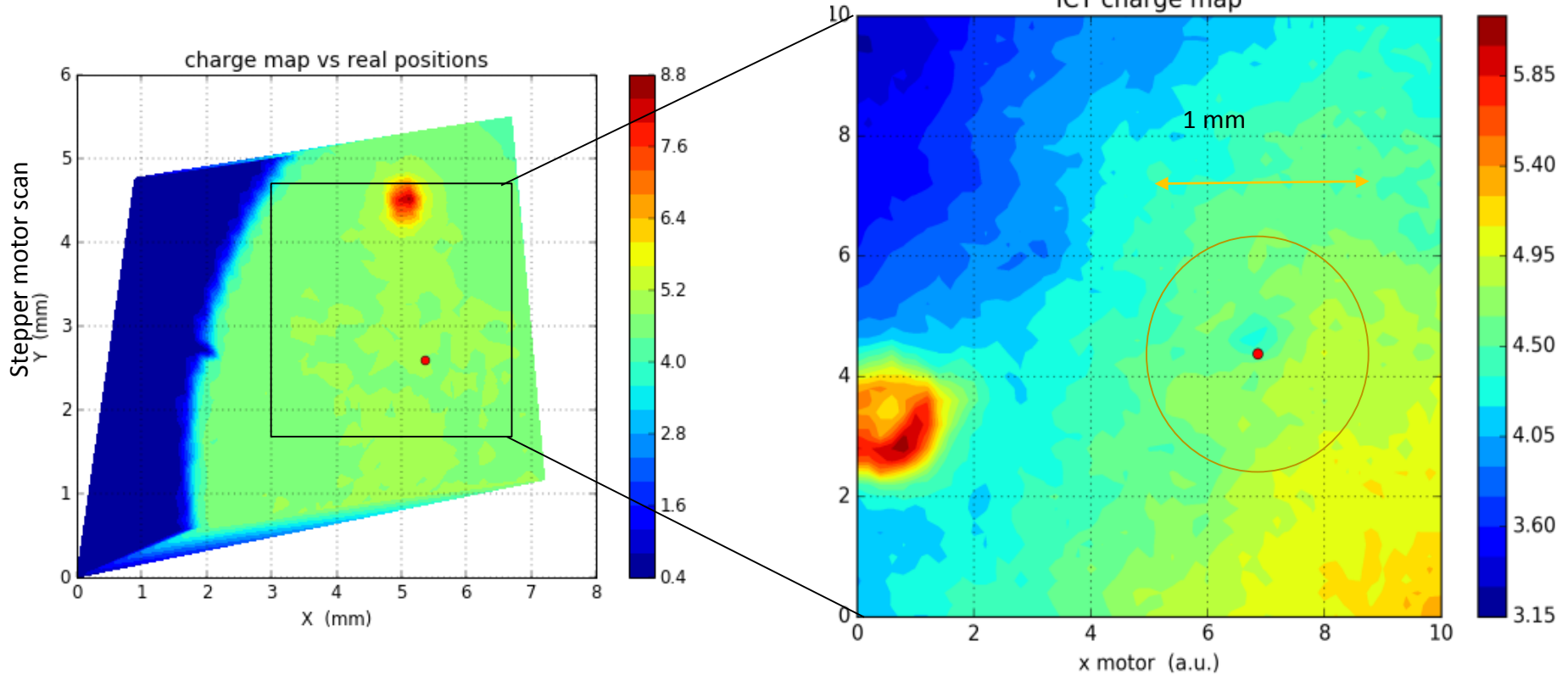
Cathode imaging with e-beam on YAG



No defects clearly visible

Courtesy of N. Hiller

Uniformity of Cathode#31



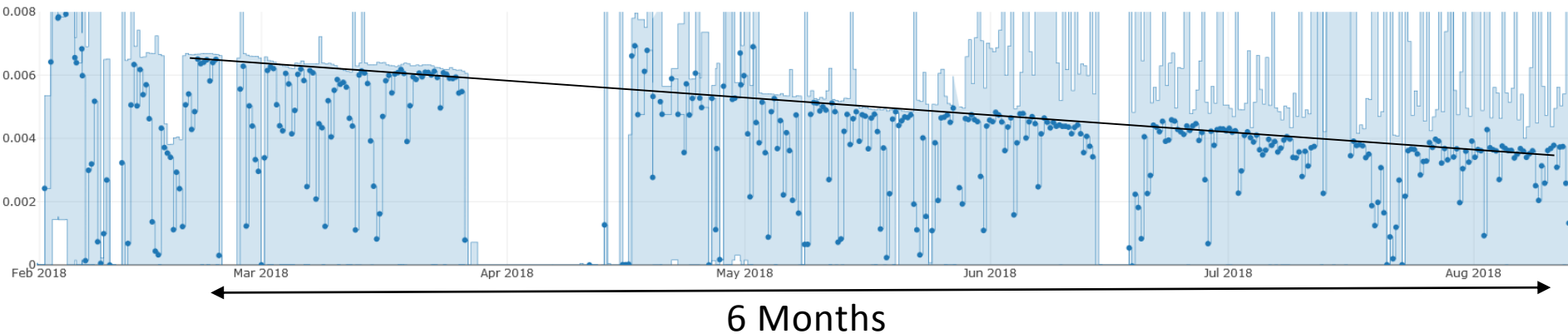
14.07.2017

18.08.2017

Uniformity $\delta_{QE}/QE \sim 15 \%$

QE scans: 5 pC; $\sigma_{r,laser} \sim 100 \mu\text{m}$

QE evolution in SwissFEL Gun



Averaged QE dropped by 40% after 6 Months

or after ~ 15 mC of charge extraction

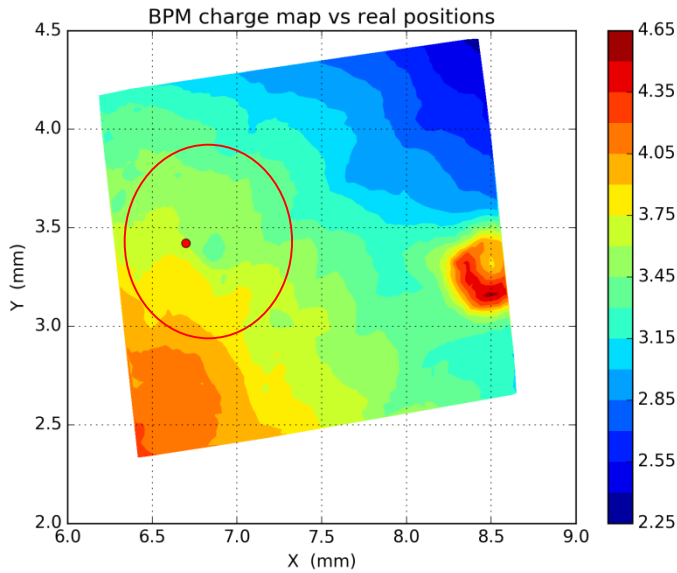
$P_{\text{cathode}} < 1 \cdot 10^{-9}$ mbar ($1.1 \cdot 10^{-11}$ mbar at the pump)

Influence of Cu substrate ?

Lifetime until $QE \sim 0.1\% > 1$ year

Cathode #31 (Cs_2Te)
 10 Hz; 200 pC
 100 MV/m

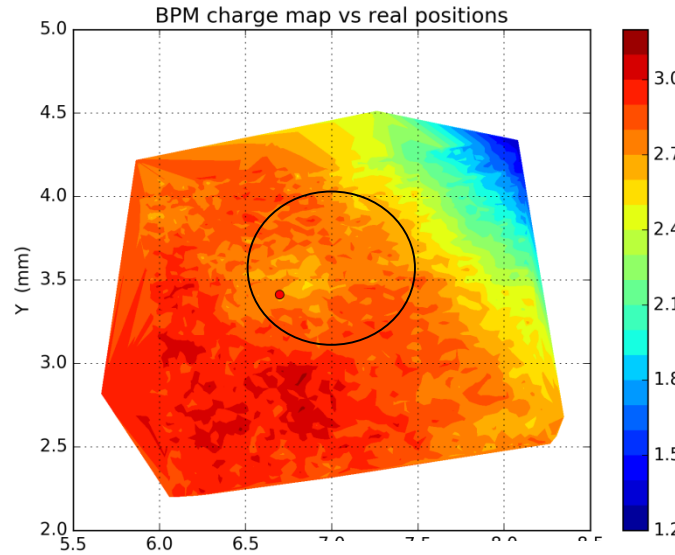
Cathode emission uniformity



02 Sept. 2017:
Uniformity $\delta_{QE}/QE \sim 15\%$

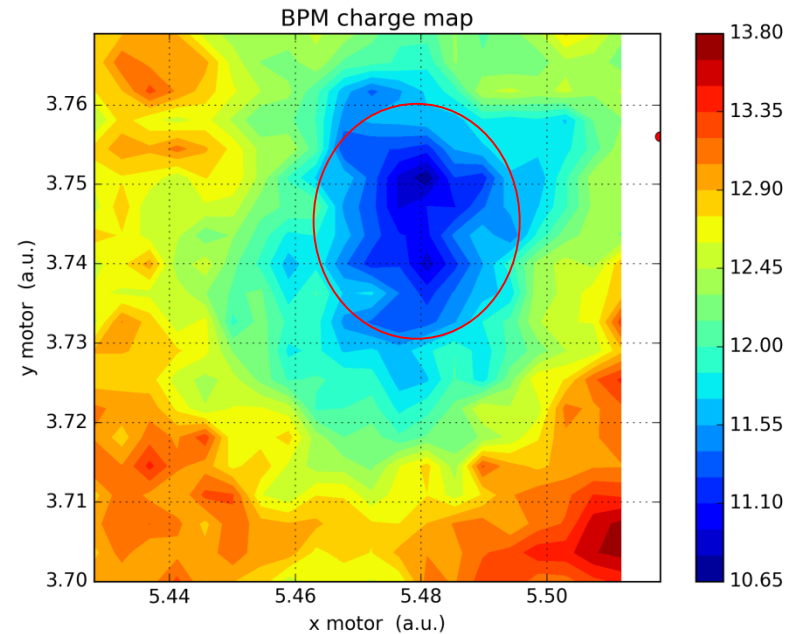
Cathode started to develop a
QE hole in recent months !

Cathode #31



31 Jul. 2018
Uniformity
 $\delta_{QE}/QE \sim 10\%$

22 Dec. 2017
Uniformity
 $\delta_{QE}/QE \sim 13\%$



Slice emittance / Intrinsic emittance

Expected Intrinsic emittance

$$\mathcal{E}_{\text{Intrinsic, Simple}} = \sigma_{x, \text{laser}} \sqrt{\frac{h\nu - \Phi_{\text{eff}}}{3mc^2}}$$

$$\sigma_{x, \text{laser}} = 0.148 \text{ mm}$$

$$\Phi_{\text{Cs}_2\text{Te}} = 3.5 \text{ eV}$$

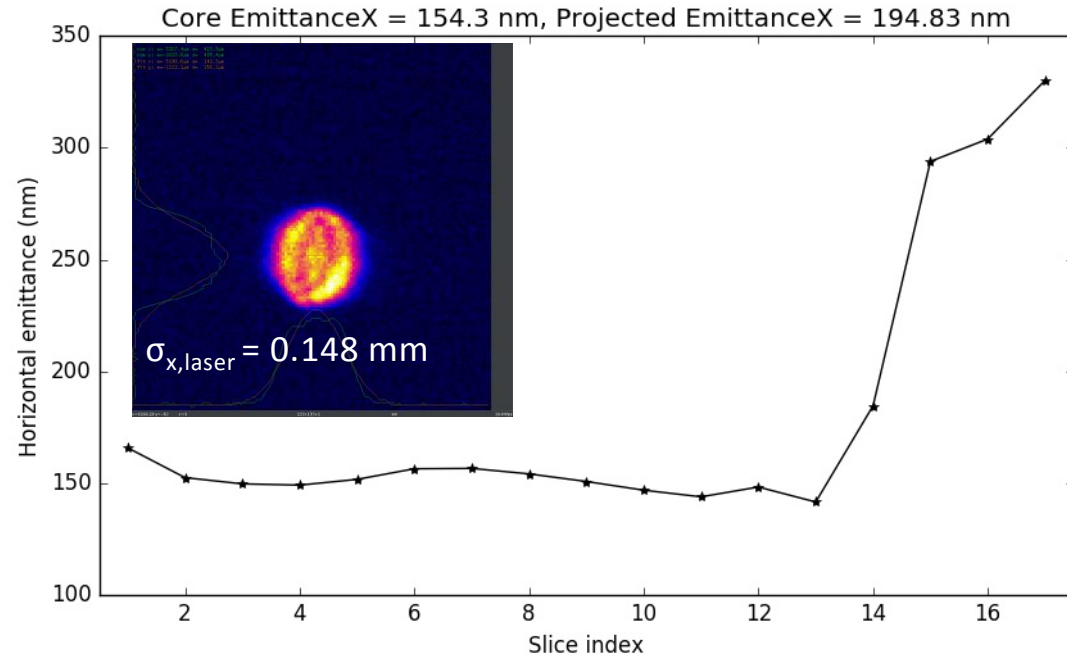
$$F = 50 \text{ MV/m}$$

$$\Phi_{\text{eff}} = 3.23 \text{ eV}$$

$$h\nu = 4.77 \text{ eV}$$

$$\mathcal{E}_{\text{intrinsic}} = 145 \text{ nm.rad}$$

Measured slice emittance



$$\mathcal{E}_{\text{slice}} = 155 \text{ nm.rad}$$

Charge 200 pC; 300 MeV

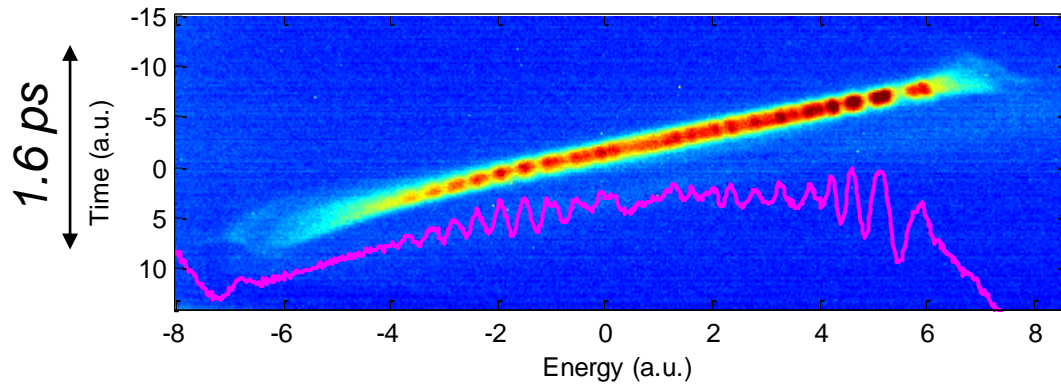
Measured slice emittance close to Intrinsic emittance !

~ Copper emittance (Phys. Rev. ST Accel. Beams 18, 043401 (2015))

Courtesy of E. Prat

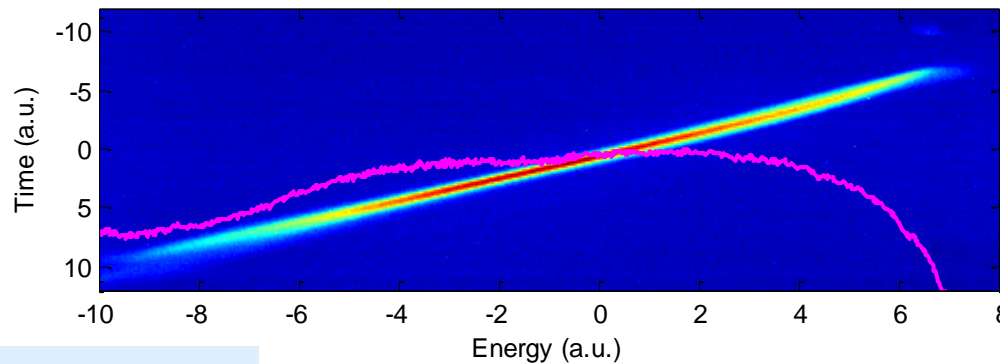
Reducing microbunching gain with Cs₂Te

Beam longitudinal phase space after compression



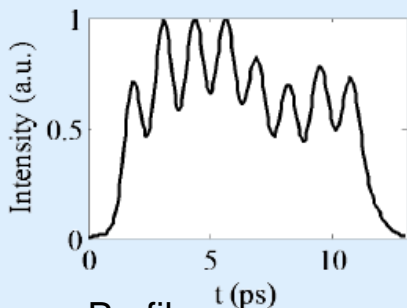
200 MeV; Factor 6 compression

Cu photocathode
100 pC, ~ 60 A



Cs₂Te photocathode
200 pC, ~ 120 A

Slower extraction smooths out the longitudinal charge modulation induced by the profile of the illuminating laser.



Laser Profile

Results from SITF 2014 - Courtesy of S. Bettoni

Small microbunching gain at SwissFEL

- Cs_2Te smooths out the laser profile ripples (more than Cu)
- Microbunching instabilities seems small at SwissFEL

=> Slow cathodes limits microbunching instability gain ?

BUT

- LCLS Simulations showed that Microbunching comes from “shot noise” even if laser profile is ideally flat !
- SACLA observed microbunching instabilities with thermionic gun !



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SwissFEL Cathode Preparation system

Microscope camera

Cathode annealing
QE measuring chamber

Linking Chamber

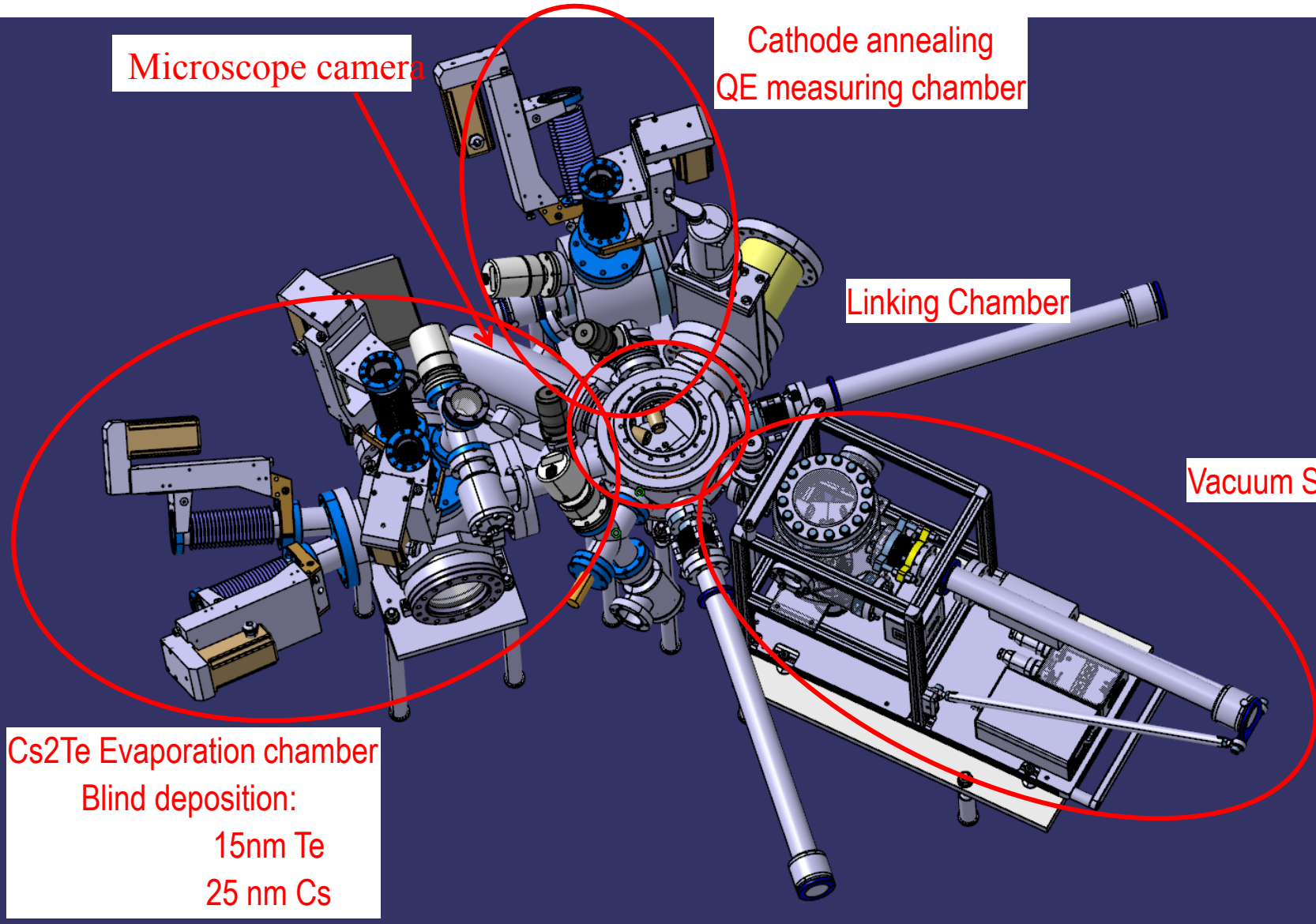
Vacuum Suitcase

Cs₂Te Evaporation chamber

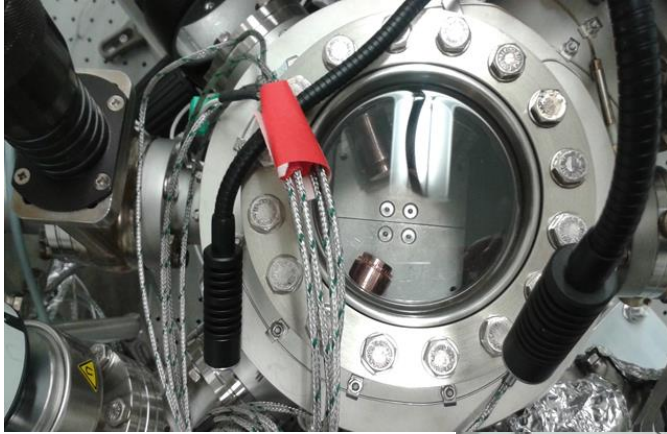
Blind deposition:

15nm Te

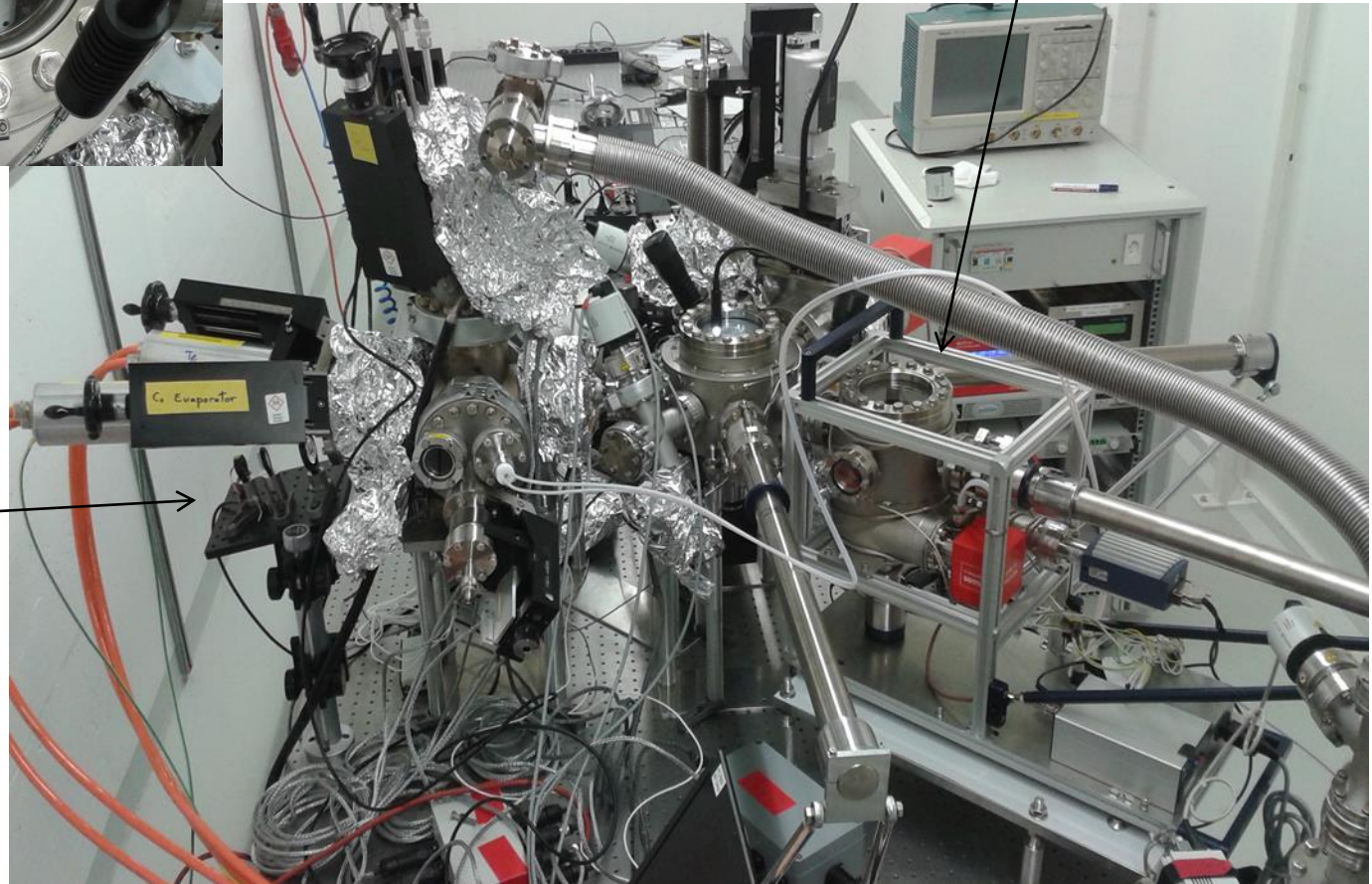
25 nm Cs



SwissFEL Cathode Preparation system



Vacuum Suitecase

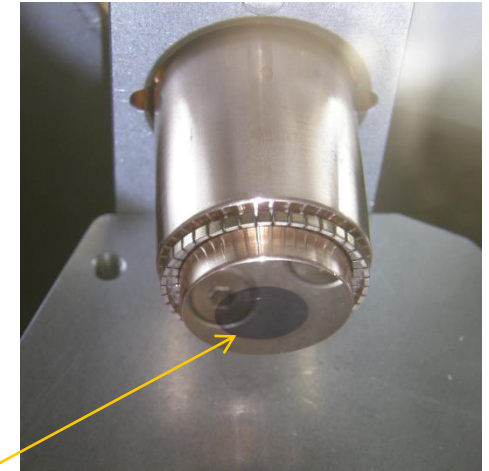
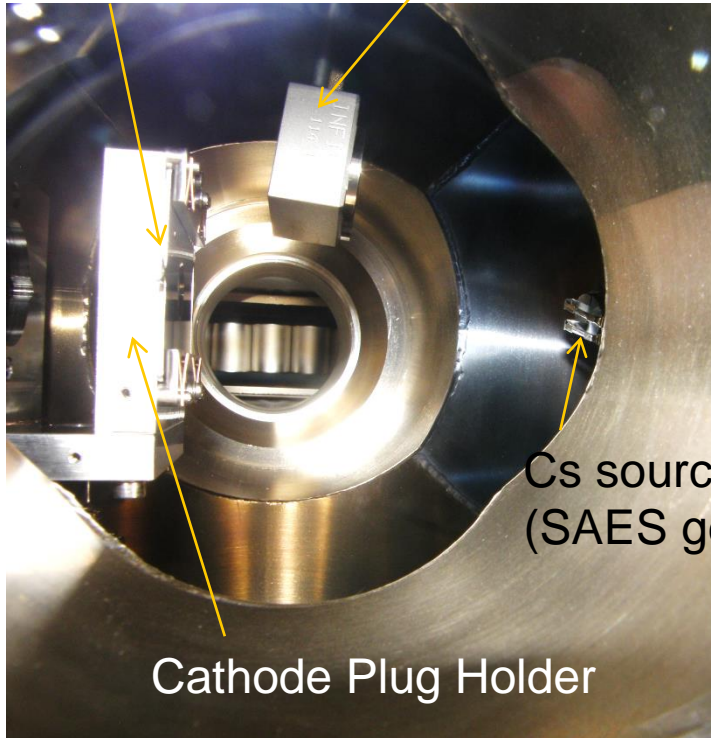


266nm LED
for QE monitoring

Cs₂Te Deposition

Aperture (in front of cathode)

Quartz micro-balance

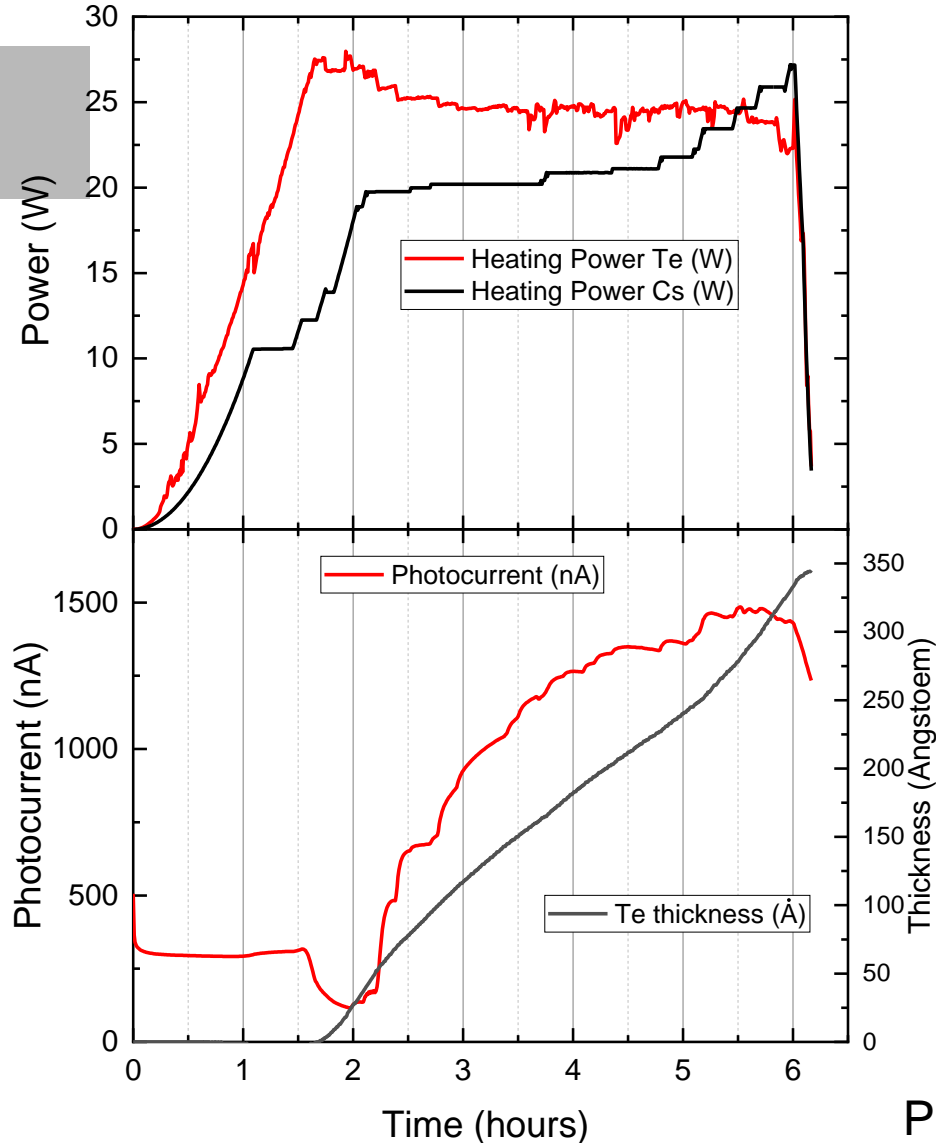


Cs₂Te layer
($\varnothing=1\text{cm}$; 40 nm)

- **successive deposition of Te and then Cs**
(recipe from CERN: CERN - CLIC Note 299 – E. Chevallay)
- **Coevaporation of Cs and Te**

Cs₂Te co-evaporation on Cu Plug

Co-evaporation Cs and Te on Cu_28; V_{anode}=100V
- 17.05.2018

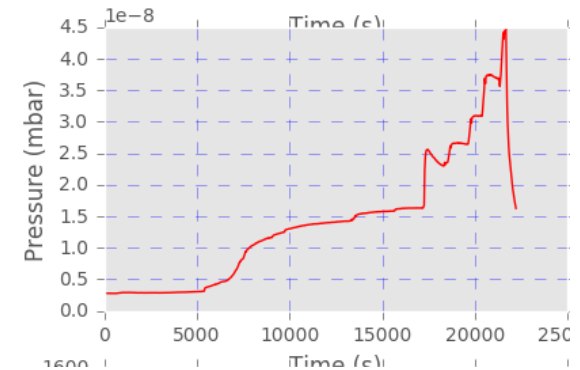


Recipe:

- Cu plug annealed 10 h at 250 deg C
- Co-evaporation while monitoring photocurrent

Difficulty:

- Control of stoichiometry
(Cs source heats Te source !)
- No independent Cs thickness monitoring

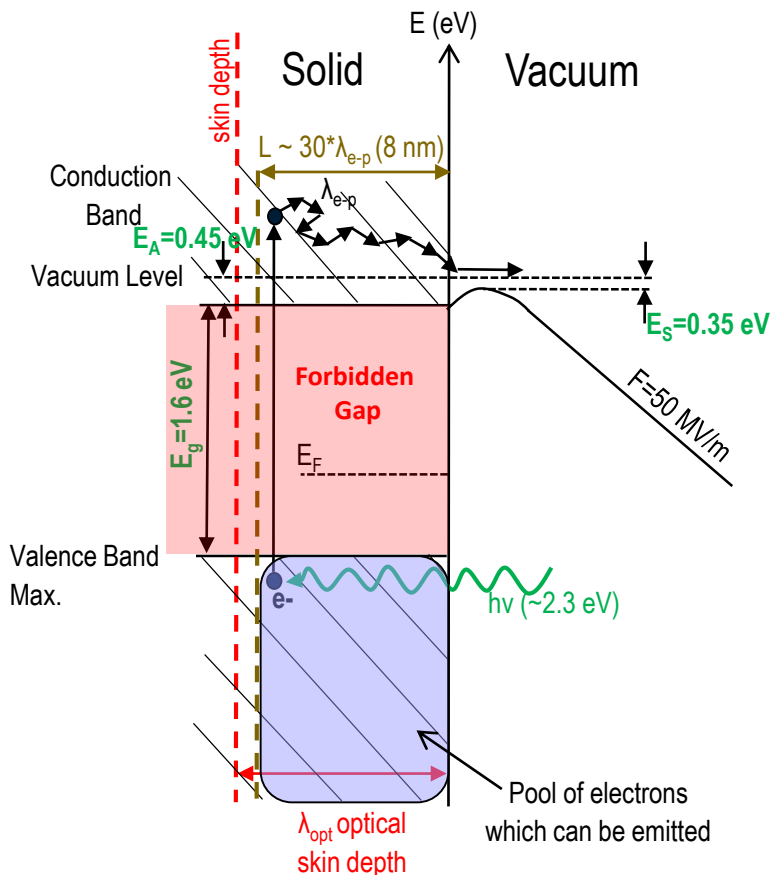


Pressure rises from 10⁻¹⁰ to 10⁻⁸ mbar

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- **Cs₃Sb coating attempts**
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Motivation for Cs₃Sb :

- illuminate photocathode with 532 nm
- => Better laser shaping possible
- => Less optics degradation



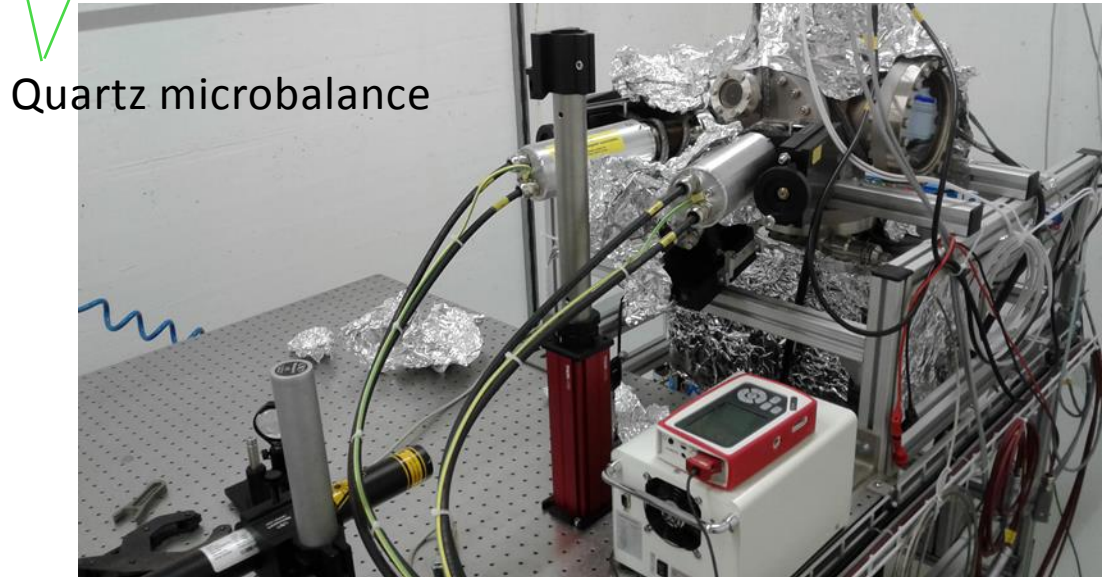
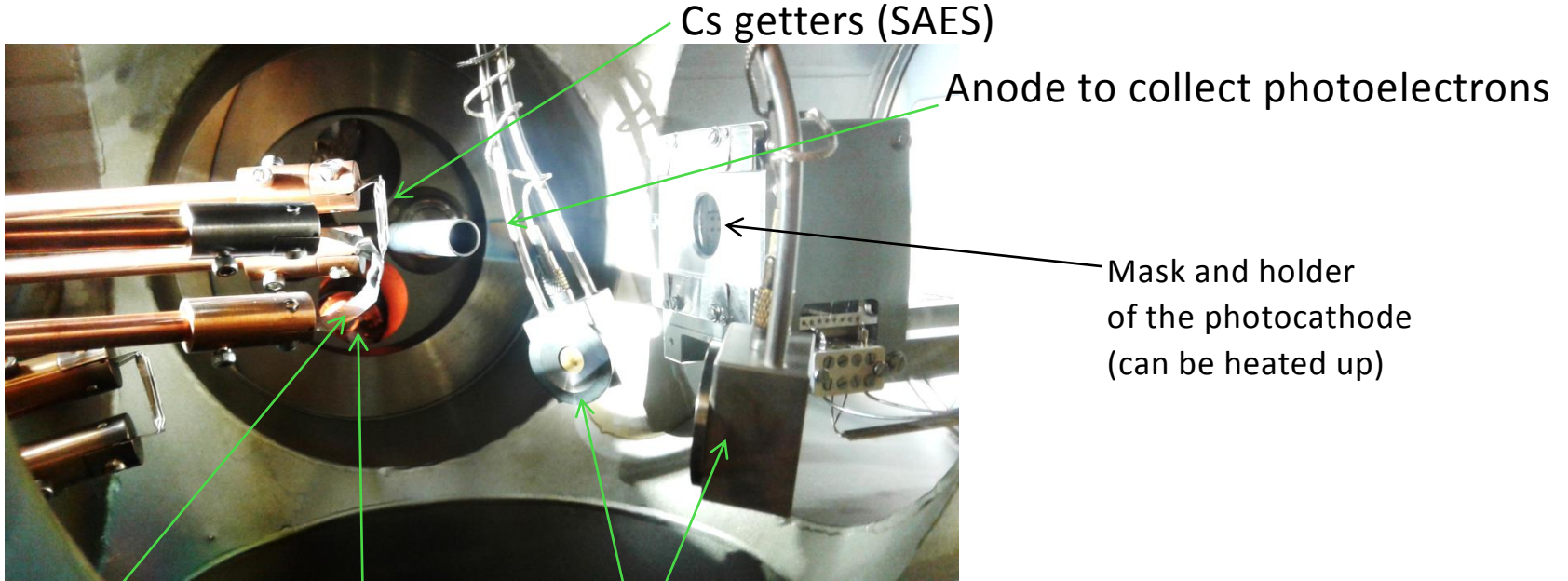
Cs₃Sb compound:

$$E_{\text{gap}} = 1.6 \text{ eV}$$

$$E_{\text{e-affinity}} = 0.45 \text{ eV}$$

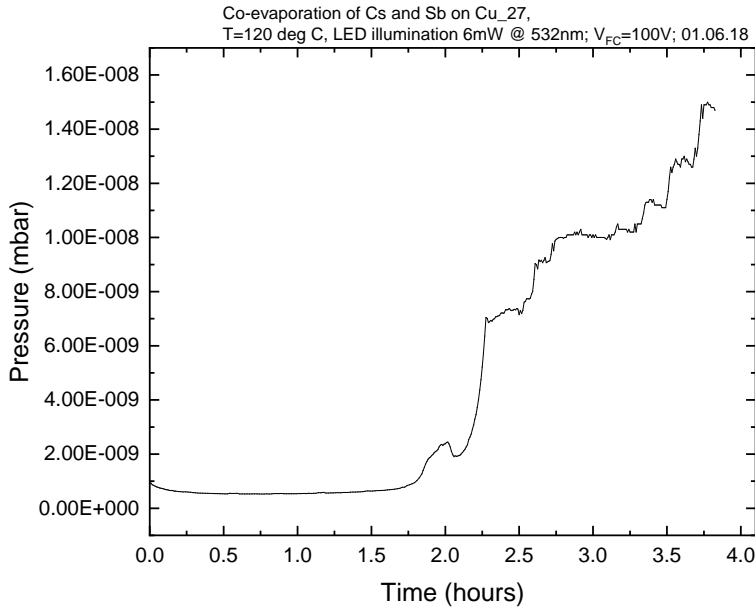
$$\Phi_{\text{eff}} = E_{\text{gap}} + E_{\text{e-affinity}} - E_{\text{schottky}} = 1.7 \text{ eV}$$

Evaporation chamber for Cs₃Sb



$P \sim 1.0 \cdot 10^{-11}$ mbar

Co-Evaporation Cs & Sb



Recipe:

Sb heating power has to be reduced !

Deposition rate Sb: 0.01 – 0.02 Å/s

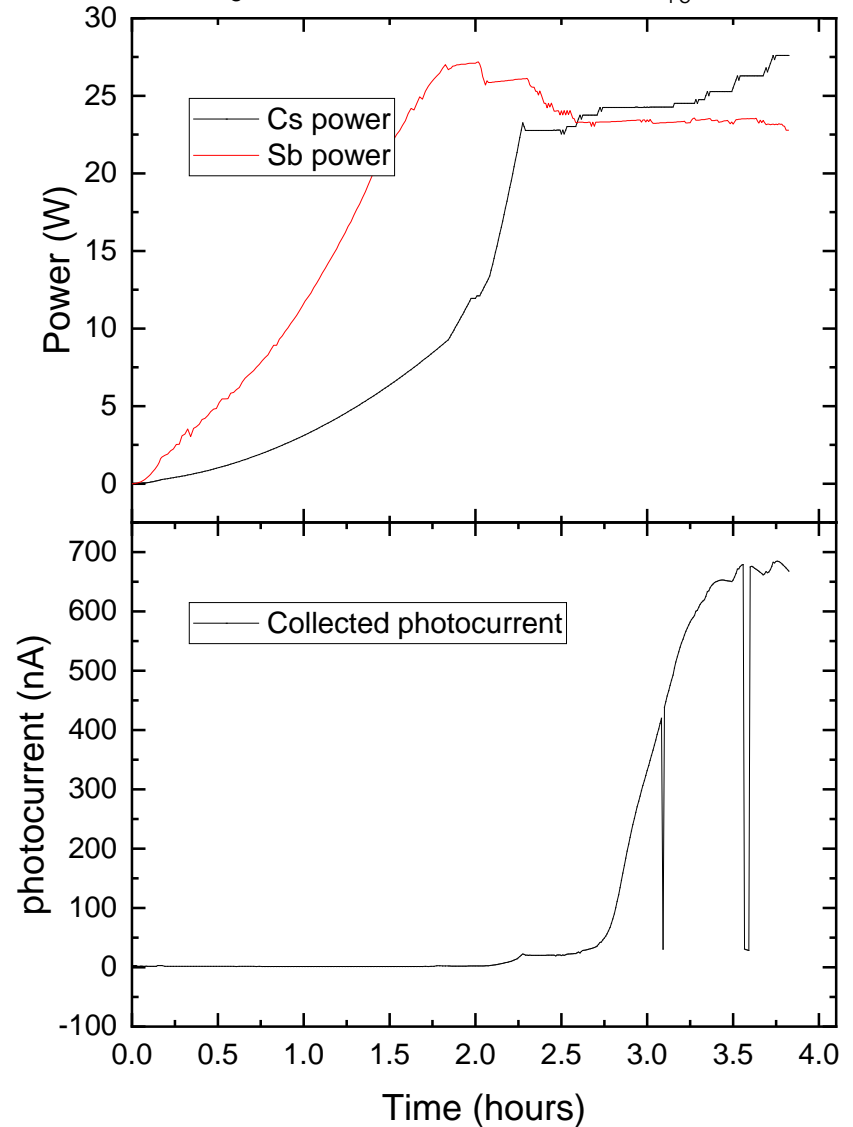
Deposition rate Cs: 0.1 Å/s

T_{cathode} = 120°C,

Pressure increases to 1.5e-8 mbar

DC illumination with 532nm LED

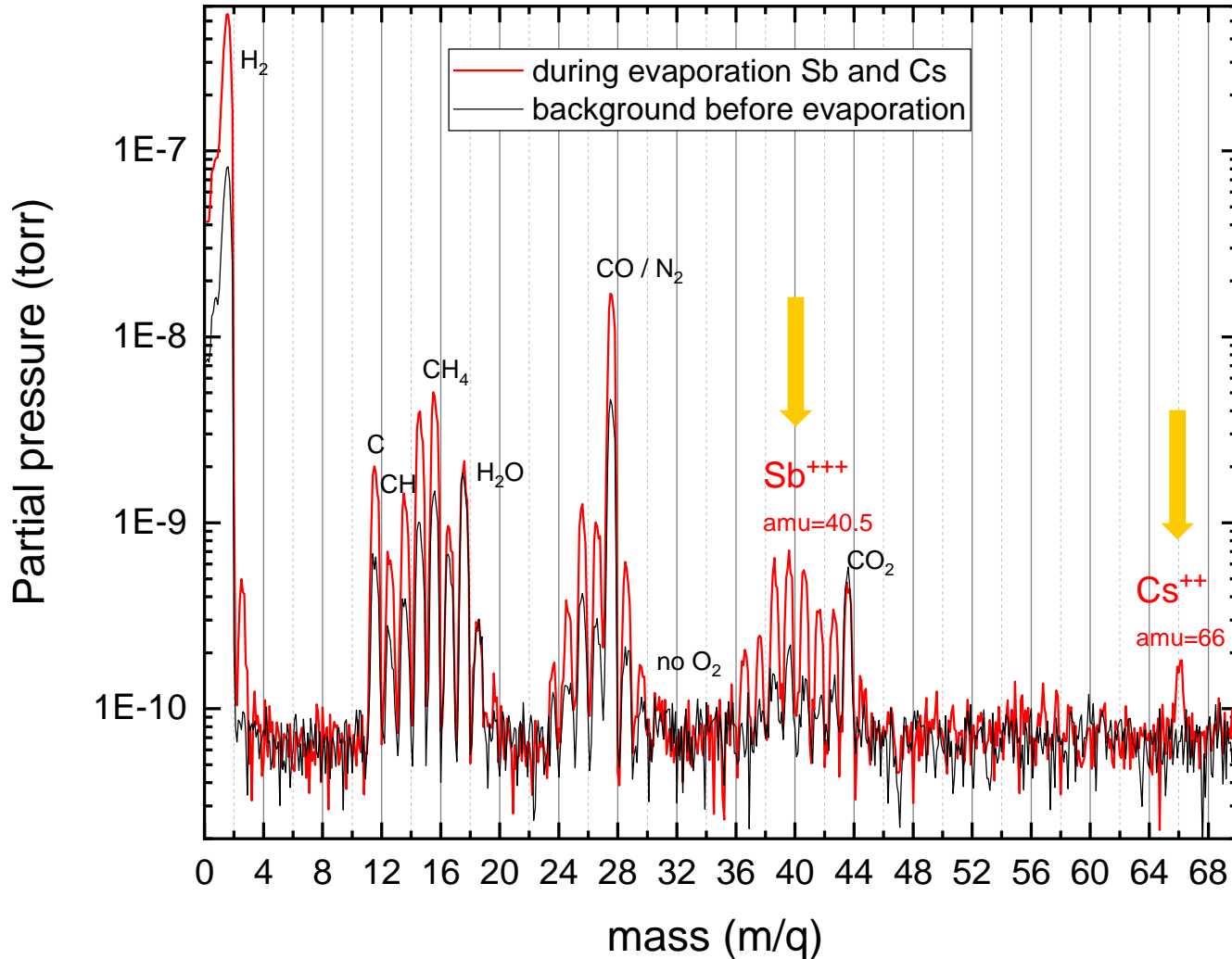
Co-evaporation of Cs and Sb on Cu_27,
T=120 deg C, LED illumination 6mW @ 532nm; V_{FC}=100V; 01.06.18



RGA during co-evaporation

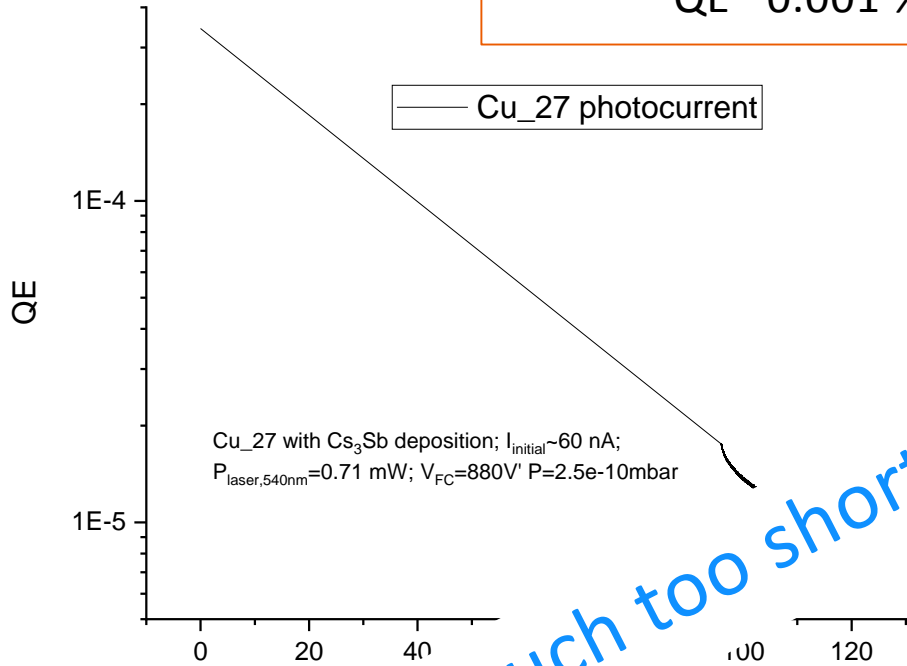
Sb evaporator heats up with Cs evaporator

RGA mass spectrum in the evaporation chamber: Sb and Cs
 Total pressure went from 5e-10 mbar to 1.5e-8 mbar

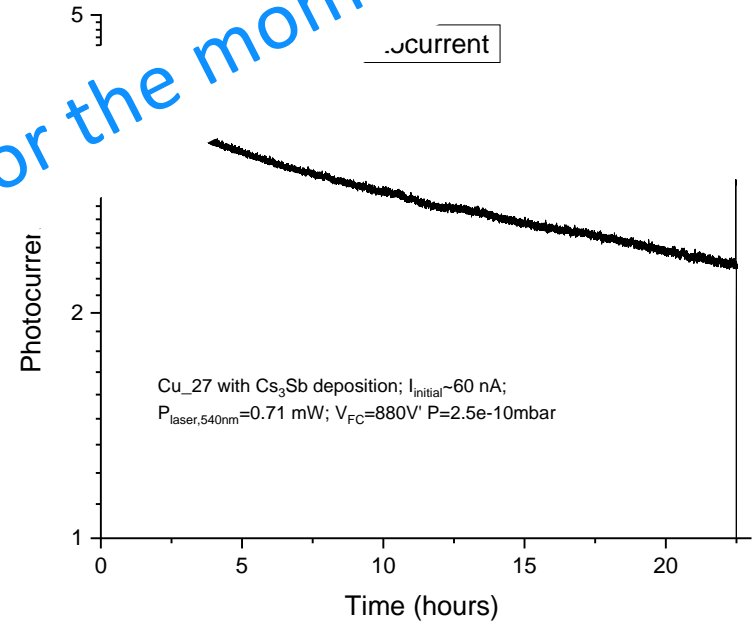


QE Lifetime of Cs₃Sb cathode #27

Cs₃Sb: QE ~ 0.6% at end of deposition (650 nA)
 QE ~ 0.1 % after 1 hour
 QE ~ 0.001 % after 100 hours (w/o illumination)



Lifetime much too short ... for the moment !



QE in gun factor 2 larger due to electric field.

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- Cs₂Te experience with SwissFEL user operation rather positive
- Lifetime seems > 1 year with 30 mC/year, 100 MV/m, 5.0*10⁻¹⁰ mbar
- Beam quality: slice emittance <300nm; small microbunching instabilities ?
- First Cs₃Sb coating had acceptable QE (>0.1%) but lifetime much too short

Perspectives:

- Photocathodes development with sensitivity to green light
 - Cs₂Te with Ge doping to reduce bandgap (532nm)
 - CdTe with Cs activation to reduce electron affinity

European Photocathode Workshop

11-13 September 2019 – PSI (Switzerland)

<https://indico.psi.ch/internalPage.py?pageId=0&confId=6746>



EWPA 2019: European Workshop on Photocathodes for Particle Accelerator Applications

11-13 September 2019 Paul Scherrer Institut; CH-5232J Villigen PSI; Hörsaal PSI Bildungszentrum: OSGA/EG06
Europe/Zurich timezone

Welcome to EWPA 2019!

Dear Colleagues,

It is our pleasure to announce that the **European Workshop on Photocathodes for Particle Accelerator Applications (EWPA 2019)**, will be held at the **Paul Scherrer Institut, Switzerland, from September 11 to 13, 2019.**

We invite you to participate to this workshop with focus on the recent progress in research and development of photocathodes for accelerator applications. Contributions are welcome from all related topics, including operational experience, preparation, instrumentations, theoretical modelling, industrial applications and novel materials. The scientific programme of the workshop will consist of invited talks and contributed presentations, either in the form of oral presentations or posters.

The workshop will be held from **Wednesday noon to Friday noon** with the Wednesday afternoon assigned for the poster session and Thursday afternoon for a visit at the SwissFEL facility and the photocathode laboratory as well as the workshop dinner.

Registration and abstract submission will be opened in March 2019.

Scientific Programme Committee

Julius Kühn (HZB)
Thorsten Kamps (HZB)
Tim Noakes (UKRI STFC)
Lee Jones (UKRI STFC)
Rong Xiang (HZDR)
Antonella Lorusso (INFN Lecce)
Christoph Hessler (CERN)
Romain Ganter (PSI)

Welcome

Programm

Registration

Registration Form

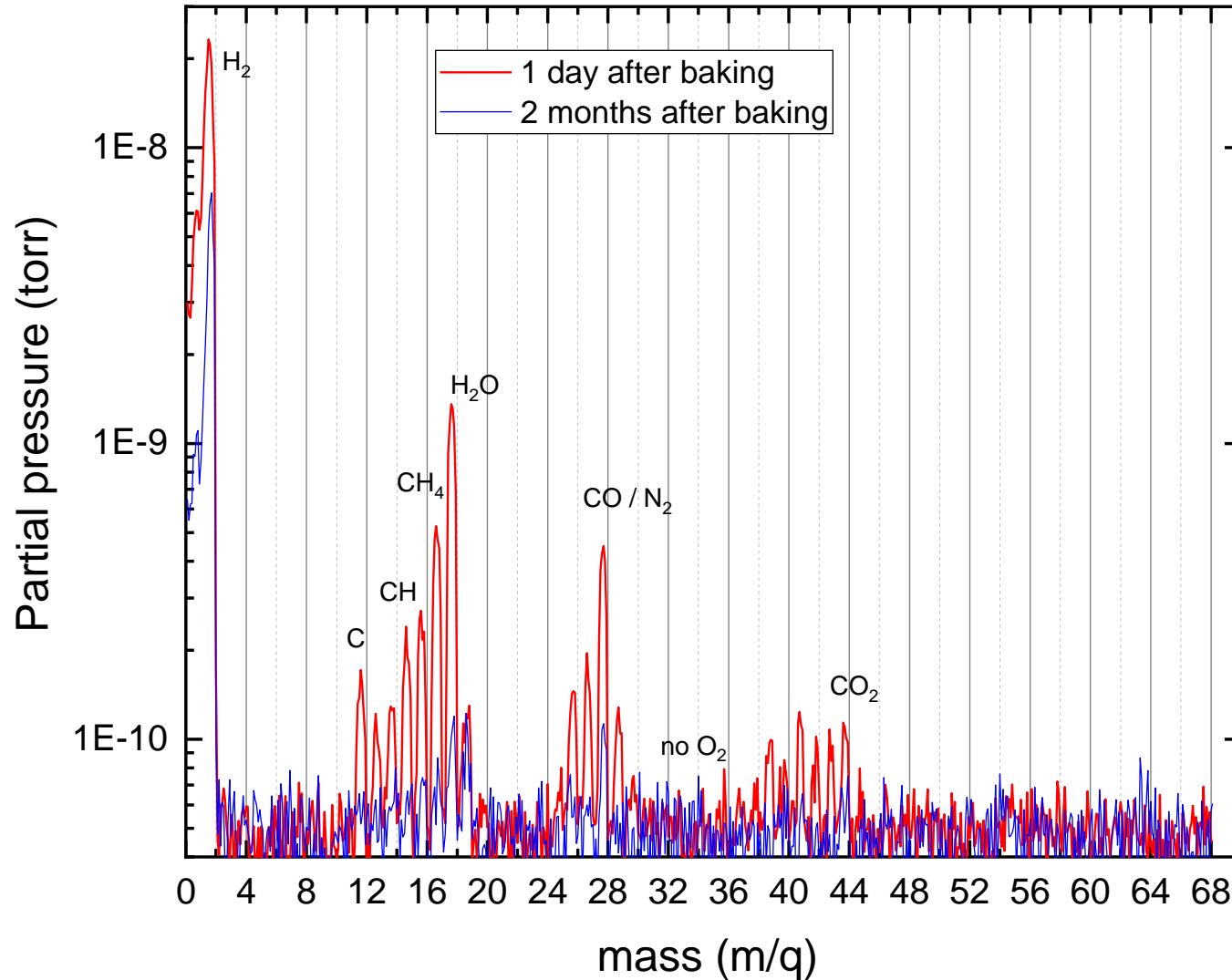
Venue

Accommodation

Contact

Background Vacuum

RGA mass spectrum in the evaporation chamber: Sb and Cs after 100 h baking at 250 deg C
Total pressure $9. \times 10^{-11}$ mbar - 17.07.2018



Aramis FEL pulses:

E_{Photons} : max 12.4 keV

Achieved FEL Pulse Energy:

570 μJ at 3 keV

400 μJ at 6 keV

... still under improvement

